



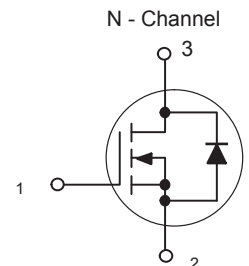
200 mAmp N Channel Power MOSFET - 50 Volts

N-Channel SOT-23

Typical applications are dc-dc converters, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low Threshold Voltage ($V_{GS(th)}$: 0.5V...1.5V) makes it ideal for low voltage applications
- Miniature SOT-23 Surface Mount Package saves board space
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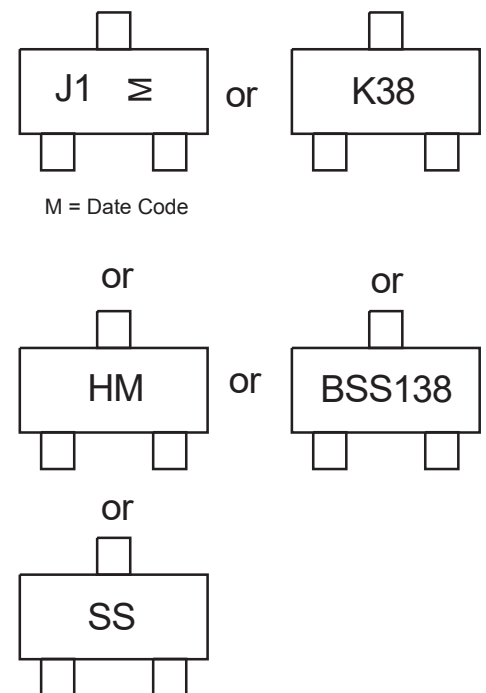
SOT -23



MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSS}	50	Vdc
Gate-to-Source Voltage – Continuous	V_{GS}	± 20	Vdc
Drain Current – Continuous @ $T_A = 25^\circ\text{C}$ – Pulsed Drain Current ($t_p \leq 10 \mu\text{s}$)	I_D I_{DM}	200 800	mA
Total Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	225	mW
Operating and Storage Temperature Range	T_J, T_{stg}	- 55 to 150	$^\circ\text{C}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Maximum Lead Temperature for Soldering Purposes, for 10 seconds	T_L	260	$^\circ\text{C}$

MARKING DIAGRAM & PIN ASSIGNMENT



J1\K38\HMBSS138\SS = Device

Code **ORDERING INFORMATION**

Device	Package	Shipping
BSS138LT1	SOT-23	3000 Tape & Reel

**200 mAmp N Channel Power MOSFET - 50 Volts****ELECTRICAL CHARACTERISTICS** ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Drain-to-Source Breakdown Voltage ($V_{GS} = 0\text{ Vdc}$, $I_D = 250\text{ }\mu\text{Adc}$)	$V_{(BR)DSS}$	50	—	—	Vdc
Zero Gate Voltage Drain Current ($V_{DS} = 25\text{ Vdc}$, $V_{GS} = 0\text{ Vdc}$) ($V_{DS} = 50\text{ Vdc}$, $V_{GS} = 0\text{ Vdc}$)	I_{DSS}	— —	— —	0.1 0.5	μAdc
Gate-Source Leakage Current ($V_{GS} = \pm 20\text{ Vdc}$, $V_{DS} = 0\text{ Vdc}$)	I_{GSS}	—	—	± 0.1	μAdc

ON CHARACTERISTICS (Note 1.)

Gate-Source Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 1.0\text{ mAdc}$)	$V_{GS(th)}$	0.5	—	1.5	Vdc
Static Drain-to-Source On-Resistance ($V_{GS} = 2.75\text{ Vdc}$, $I_D < 200\text{ mAdc}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$) ($V_{GS} = 5.0\text{ Vdc}$, $I_D = 200\text{ mAdc}$)	$r_{DS(on)}$	— —	5.6 —	10 3.5	Ohms
Forward Transconductance ($V_{DS} = 25\text{ Vdc}$, $I_D = 200\text{ mAdc}$, $f = 1.0\text{ kHz}$)	g_{fs}	100	—	—	mmhos

DYNAMIC CHARACTERISTICS

Input Capacitance	($V_{DS} = 25\text{ Vdc}$, $V_{GS} = 0$, $f = 1\text{ MHz}$)	C_{iss}	—	40	50	pF
Output Capacitance	($V_{DS} = 25\text{ Vdc}$, $V_{GS} = 0$, $f = 1\text{ MHz}$)	C_{oss}	—	12	25	
Transfer Capacitance	($V_{DG} = 25\text{ Vdc}$, $V_{GS} = 0$, $f = 1\text{ MHz}$)	C_{rss}	—	3.5	5.0	

SWITCHING CHARACTERISTICS (Note 2.)

Turn-On Delay Time	($V_{DD} = 30\text{ Vdc}$, $I_D = 0.2\text{ Adc}$,)	$t_{d(on)}$	—	—	20	ns
Turn-Off Delay Time		$t_{d(off)}$	—	—	20	

1. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2\%$.
2. Switching characteristics are independent of operating junction temperature.



TYPICAL ELECTRICAL CHARACTERISTICS

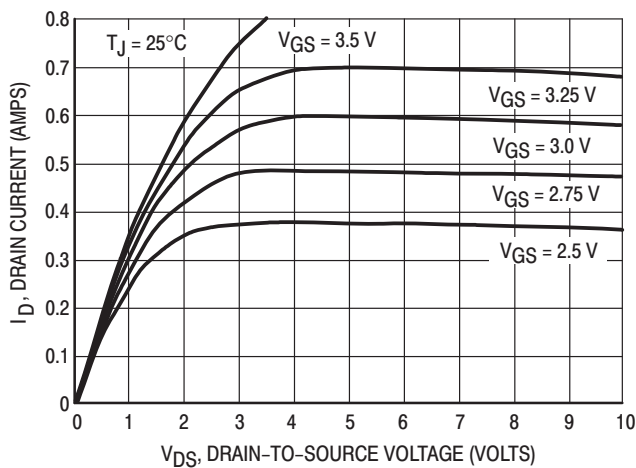


Figure 1. On-Region Characteristics

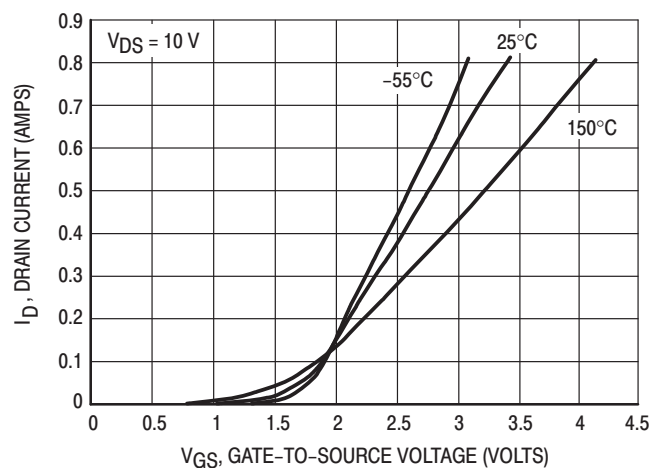


Figure 2. Transfer Characteristics

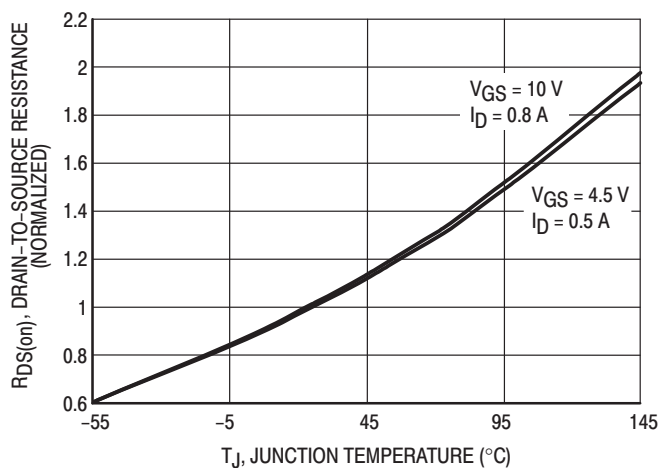


Figure 3. On-Resistance Variation with Temperature

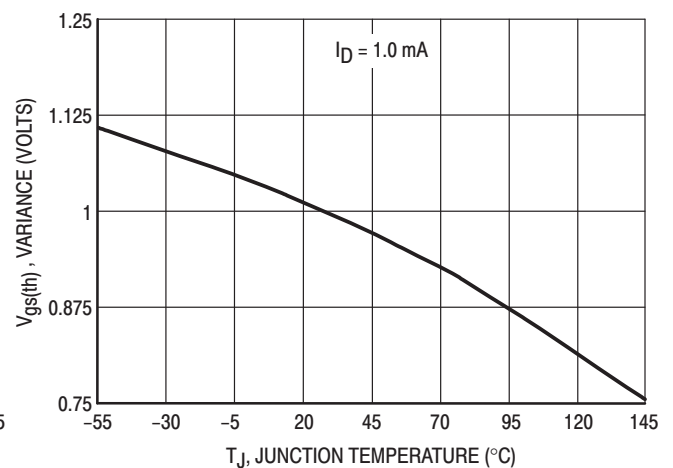


Figure 4. Threshold Voltage Variation with Temperature

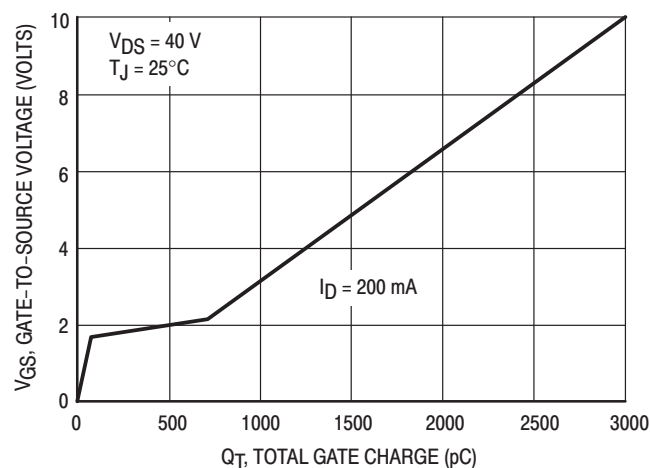


Figure 5. Gate Charge



TYPICAL ELECTRICAL CHARACTERISTICS

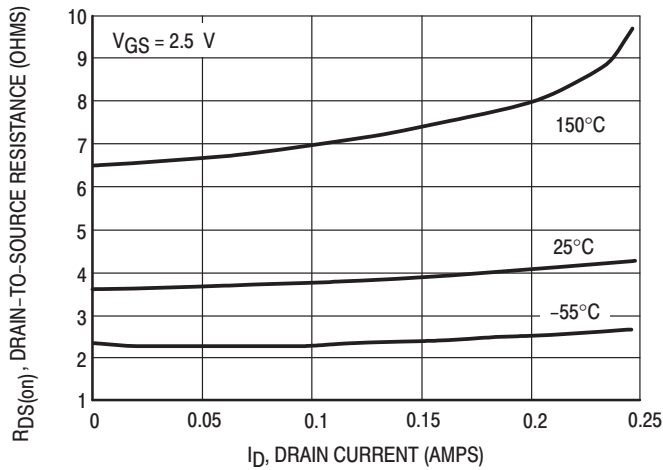


Figure 6. On-Resistance versus Drain Current

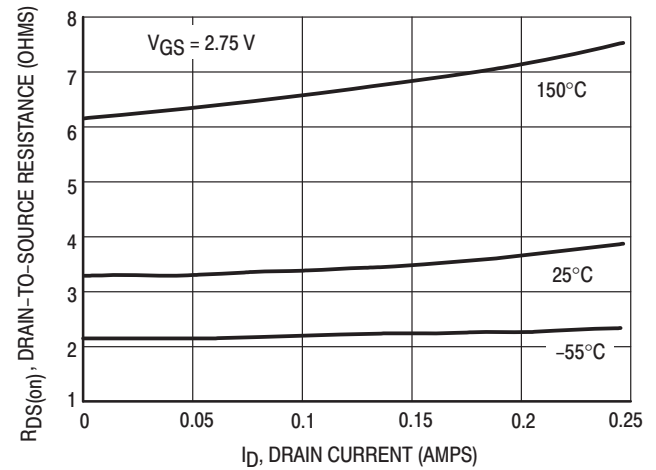


Figure 7. On-Resistance versus Drain Current

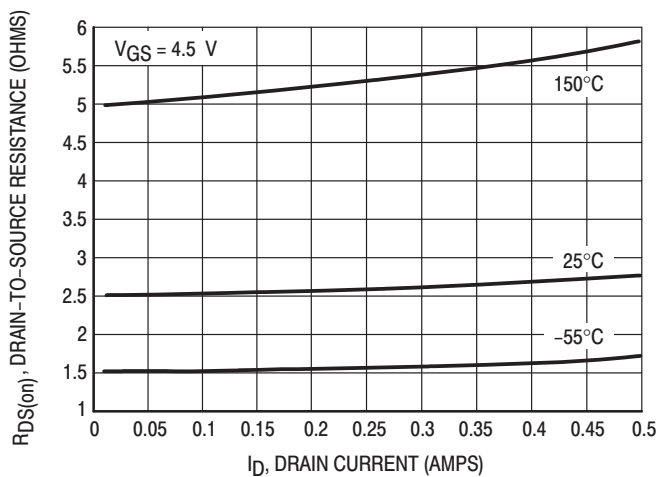


Figure 8. On-Resistance versus Drain Current

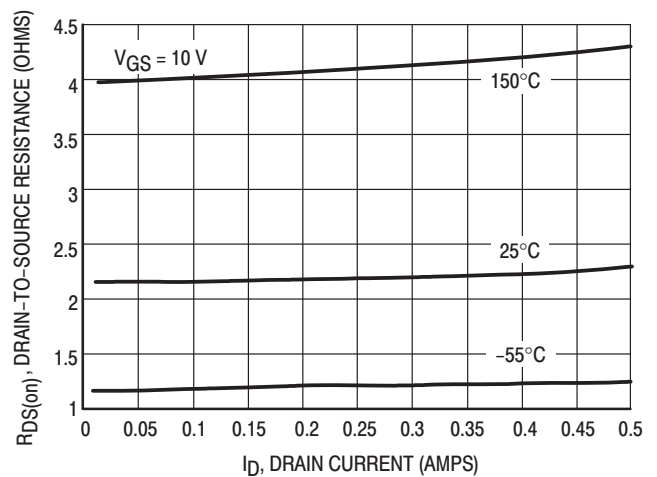


Figure 9. On-Resistance versus Drain Current

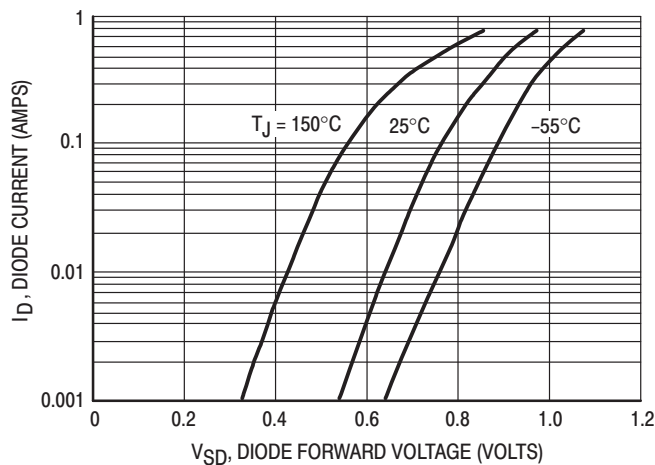


Figure 10. Body Diode Forward Voltage

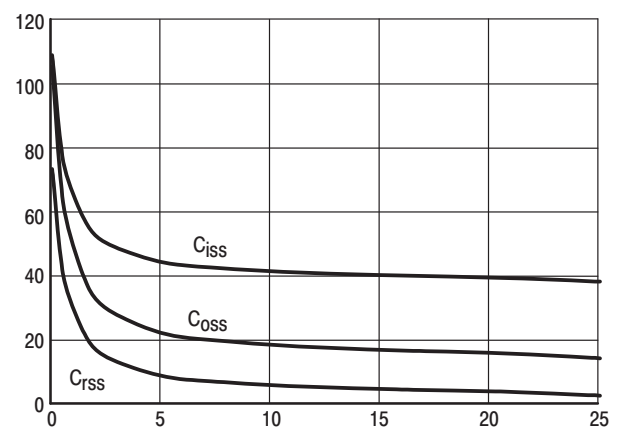
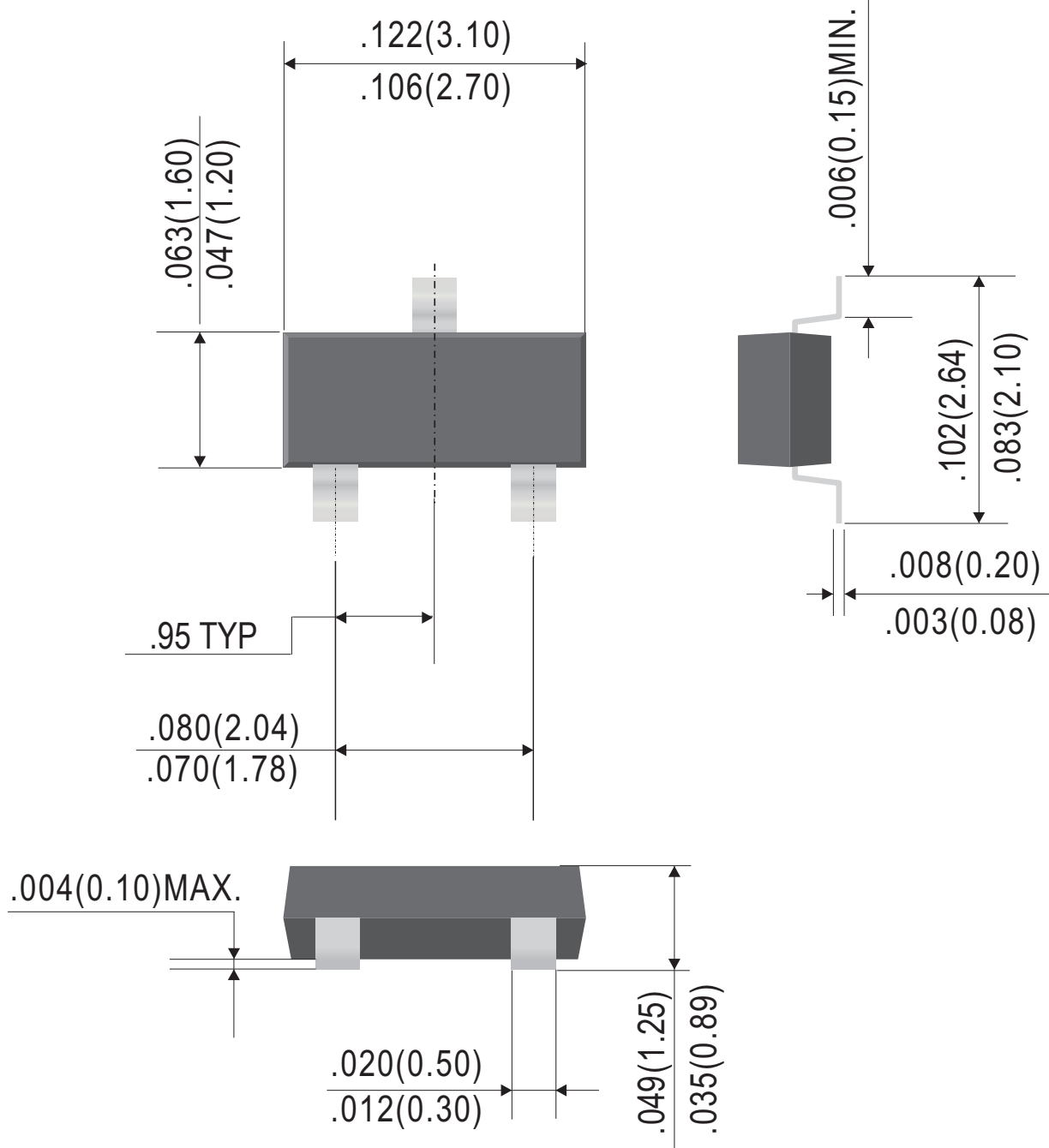


Figure 11. Capacitance



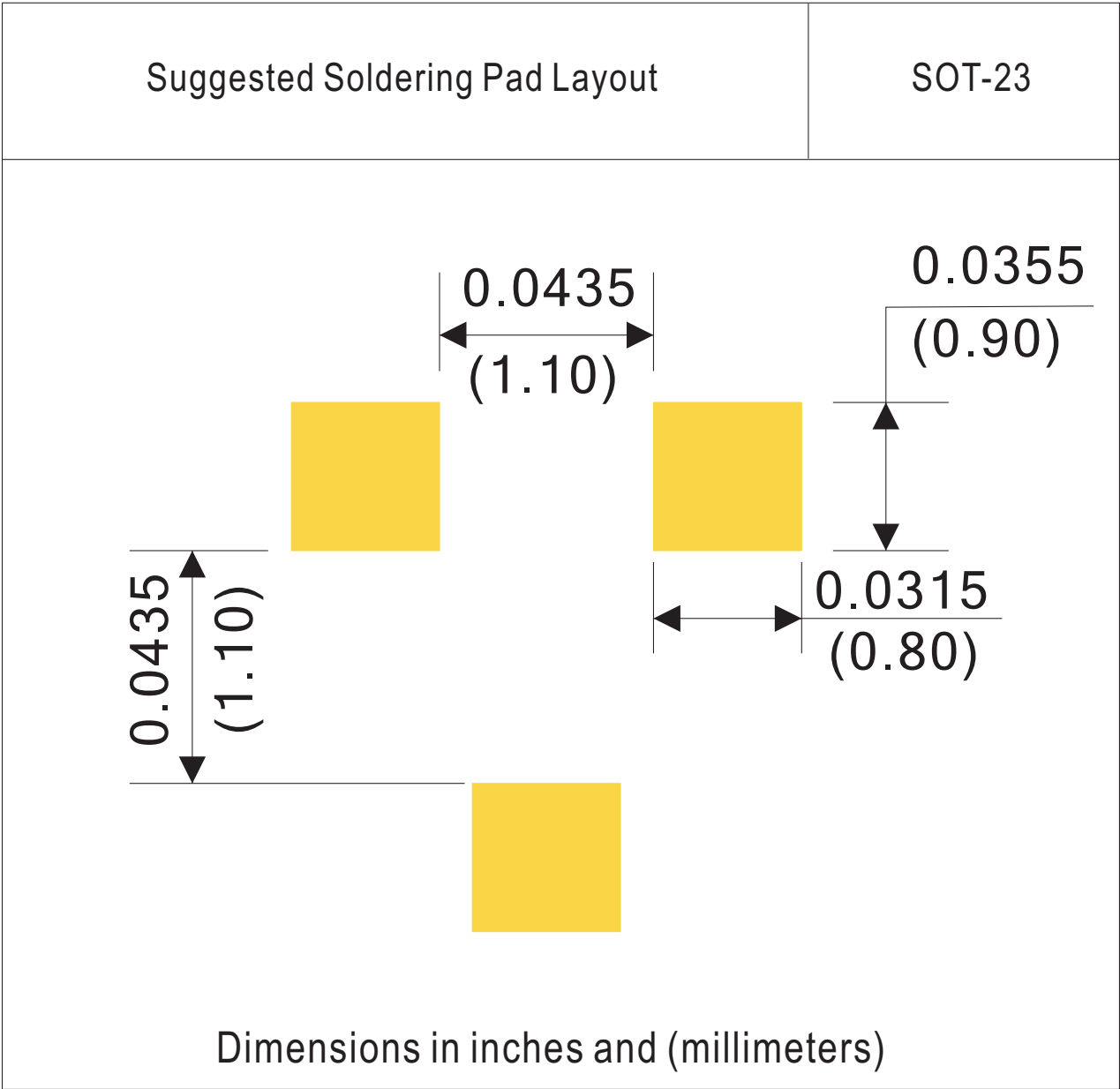
Outline Drawing

SOT-23



Dimensions in inches and (millimeters)

Rev.E



RevA



Ordering Information:

Device PN	Marking ⁽⁴⁾	Packing
BSS138LT1G ⁽¹⁾ -WS ⁽²⁾	see page 1	Tape&Reel: 3 Kpcs/Reel

Note: (1) Packing code, Tape & Reel Packing

- (2) Packing code suffix "G" for RoHS product ; Packing code Suffix "H" for halogen free product.
All materials and products supplied comply with the U.S. Toxic Substances Control Act statement, PBT Chemicals.
- (3) Willas brand abbreviation, Label Type does not display.
- (4) There may be additional marking, which relates to the lot trace code information (data code and vendor code), the logo or the environmental category on the device.

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